











#### SN74AVC4T245-Q1

SCES792B -NOVEMBER 2009-REVISED MARCH 2016

# SN74AVC4T245-Q1 4-Bit Dual-Supply Bus Transceiver With Configurable Voltage Translation and 3-State Outputs

#### **Features**

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level H3B (JESD 22 A114-A)
  - Device CDM ESD Classification Level C5 (JESD 22 C101)
- Control Input V<sub>IH</sub> and V<sub>IL</sub> Levels Are Referenced to V<sub>CCA</sub> Voltage
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant
- I<sub>off</sub> Supports Partial Power-Down-Mode Operation
- Maximum Data Rates
  - 380 Mbps (1.8-V to 3.3-V Translation)
  - 200 Mbps (<1.8-V to 3.3-V Translation)
  - 200 Mbps (Translate to 2.5 V or 1.8 V)
  - 150 Mbps (Translate to 1.5 V)
  - 100 Mbps (Translate to 1.2 V)
- Latch-Up Performance Exceeds 100 mA per JESD 78, Class II

### **Applications**

- **Telematics**
- Cluster
- Head Unit
- **Navigation Systems**

### 3 Description

This 4-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track  $V_{CCA}.\ V_{CCA}$  accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V<sub>CCB</sub>. V<sub>CCB</sub> accepts any supply voltage from 1.2 V to 3.6 V. The SN74AVC4T245-Q1 is optimized to operate with  $V_{\text{CCA}}\!/\!V_{\text{CCB}}$  set at 1.4 V to 3.6 V. It is operational with V<sub>CCA</sub>/V<sub>CCB</sub> as low as 1.2 V. This universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

The SN74AVC4T245-Q1 designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I<sub>CC</sub> and I<sub>CCZ</sub>.

The SN74AVC4T245-Q1 is designed so that the control pins (1DIR, 2DIR,  $1\overline{OE}$ , and  $2\overline{OE}$ ) are supplied by V<sub>CCA</sub>.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$  . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V<sub>CC</sub> isolation feature ensures that if either V<sub>CC</sub> input is at GND, then both ports are in the highimpedance state.

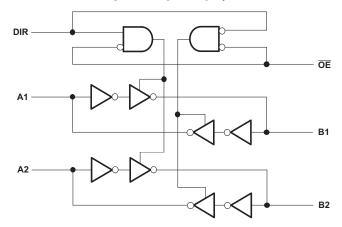
To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74AVC4T245-Q1	VQFN (16)	4.00 mm × 3.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245-Q1





### **Table of Contents**

pplications 1 escription 1 evision History 2 n Configuration and Functions 3 pecifications 4	9	8.1 Overview  8.2 Functional Block Diagram  8.3 Feature Description  8.4 Device Functional Modes.	15 16
escription	۵	8.3 Feature Description	16
evision History	a	•	
n Configuration and Functions 3	0	8.4 Device Functional Modes	16
_	۵		
	Э	Application and Implementation	17
		9.1 Application Information	17
		9.2 Typical Application	17
•	10	Power Supply Recommendations	19
	11	Layout	19
		11.1 Layout Guidelines	19
o con	12	Device and Documentation Support	20
557.		12.1 Documentation Support	20
		12.2 Trademarks	20
5		12.3 Electrostatic Discharge Caution	20
12 Typical Characteristics	13	Mechanical, Packaging, and Orderable	20
· .	.1 Absolute Maximum Ratings       4         .2 ESD Ratings       4         .3 Recommended Operating Conditions       4         .4 Thermal Information       5         .5 Electrical Characteristics       5         .6 Switching Characteristics: V <sub>CCA</sub> = 1.2 V       7         .7 Switching Characteristics, V <sub>CCA</sub> = 1.5 V ± 0.1 V       8         .8 Switching Characteristics: V <sub>CCA</sub> = 1.8 V ± 0.15 V       8         .9 Switching Characteristics: V <sub>CCA</sub> = 2.5 V ± 0.2 V       9         .10 Switching Characteristics: V <sub>CCA</sub> = 3.3 V ± 0.3 V       10         .11 Operating Characteristics       11	11 Absolute Maximum Ratings	9.1 Application Information

### 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision A (October 2012) to Revision B	Page
•	Added Applications section	1
•	Added -Q1 to the part number throughout the data sheet	1
•	Added Device Information table to the data sheet	1
•	Deleted Ordering Information table from the data sheet	1
•	Added Pin Functions table to the data sheet	3
•	Added ESD Ratings table to the data sheet	
•	Added Thermal Information table to the data sheet	5
•	Added Typical Characteristics to the data sheet	
•	Added Figure 1 through Figure 9 from the SN74AVC8T245-Q1 data sheet over to the <i>Typical Characteristics</i> section	
<u>•</u>	Added all new content from Application Information through the end of the data sheet	15
CI	hanges from Original (November 2009) to Revision A	Page
•	Added AEC-Q100 info to Features	1
•	Removed FSD Protection Exceeds JESD 22, 8000-V Human-Body Model (A114-A), 1000-V Charged-Device Model	

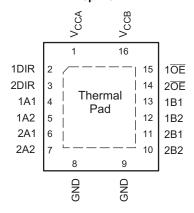
Submit Documentation Feedback

Copyright © 2009–2016, Texas Instruments Incorporated



# 5 Pin Configuration and Functions

RGY Package 16-Pin VQFN With Exposed Thermal Pad Top View



#### **Pin Functions**

PIN NAME NO.		TYPE	DESCRIPTION		
		ITPE			
1A1	4	I/O	Input/output 1A1. Referenced to V <sub>CCA</sub> .		
1A2	5	I/O	Input/output 1A2. Referenced to V <sub>CCA</sub> .		
1B1	13	I/O	Input/output 1B1. Referenced to V <sub>CCB</sub> .		
1B2	12	I/O	Input/output 1B2. Referenced to V <sub>CCB</sub> .		
1DIR	2	Ι	Direction-control input for 1 ports		
1 <del>OE</del>	15	I	3-state output-mode enable. Pull $\overline{\text{OE}}$ high to place '1' outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .		
2A1	6	I/O	Input/output 2A1. Referenced to V <sub>CCA</sub> .		
2A2	7	I/O	Input/output 2A2. Referenced to V <sub>CCA</sub> .		
2B1	11	I/O	Input/output 2B1. Referenced to V <sub>CCB</sub> .		
2B2	10	I/O	Input/output 2B2. Referenced to V <sub>CCB</sub> .		
2DIR	3	Ι	Direction-control input for 2 ports		
2 <del>OE</del>	14	I	3-state output-mode enable. Pull $\overline{\text{OE}}$ high to place '2' outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .		
GND	8, 9	_	Ground		
Thermal pad	_	_	The exposed thermal pad must be connected as a secondary GND or be left electrically open.		
$V_{CCA}$	1	1	A-port power supply voltage. 1.2 V ≤ V <sub>CCA</sub> ≤ 3.6 V		
V <sub>CCB</sub>	16	I	B-port power supply voltage. 1.2 V ≤ V <sub>CCB</sub> ≤ 3.6 V		

Product Folder Links: SN74AVC4T245-Q1



### Specifications

### 6.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating ambient temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CCA}$	Supply voltage		-0.5	4.6	٧
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage (2)	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
Vo	Voltage applied to any output in the high-impedance or	A port	-0.5	4.6	
Vo	power-off state (2)	B port	-0.5	4.6	V
V	(0) (0)	A port	-0.5	V <sub>CCA</sub> + 0.5	V
Vo	Voltage applied to any output in the high or low state (2) (3)	B port	-0.5	$V_{CCB} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND			±100	mA
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±8000		
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±1000	V	
		Machine model (C101)	±150	

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

#### 6.3 Recommended Operating Conditions (1) (2) (3)

			V <sub>CCI</sub>	V <sub>cco</sub>	MIN	MAX	UNIT	
$V_{CCA}$	Supply voltage				1.2	3.6	V	
$V_{CCB}$	Supply voltage				1.2	3.6	V	
			1.2 V to 1.95 V		V <sub>CCI</sub> × 0.65			
$V_{IH}$	High-level input voltage		1.95 V to 2.7 V		1.6		V	
			2.7 V to 3.6 V		2			
			1.2 V to 1.95 V			V <sub>CCI</sub> × 0.35		
$V_{IL}$	Low-level input voltage	Data inputs <sup>(4)</sup>	1.95 V to 2.7 V			0.7	V	
		input voltage	input voltage		2.7 V to 3.6 V			0.8
			1.2 V to 1.95 V		V <sub>CCA</sub> × 0.65			
$V_{IH}$	High-level input voltage	DIR (referenced to V <sub>CCA</sub> ) <sup>(5)</sup>	1.95 V to 2.7 V		1.6		V	
		iliput voltage	input voitage	(Loronoca to ACCV)	2.7 V to 3.6 V		2	

 $V_{\text{CCI}}$  is the  $V_{\text{CC}}$  associated with the input port.

Submit Documentation Feedback

Copyright © 2009-2016, Texas Instruments Incorporated

The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

 $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

All unused data inputs of the device must be held at V<sub>CCI</sub> or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

For  $V_{CCI}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCI} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCI} \times 0.3$  V

For  $V_{CCI}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCA} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCA} \times 0.3$  V (5)



# Recommended Operating Conditions<sup>(1) (2) (3)</sup> (continued)

			V <sub>CCI</sub>	V <sub>cco</sub>	MIN	MAX	UNIT
			1.2 V to 1.95 V			$V_{CCA} \times 0.35$	
$V_{IL}$	Low-level input voltage	DIR (referenced to V <sub>CCA</sub> ) <sup>(5)</sup>	1.95 V to 2.7 V			0.7	V
	input voltage	(Totoronood to VCCA)	2.7 V to 3.6 V			0.8	
VI	Input voltage				0	3.6	V
.,	Output valtage	Active state			0	V <sub>cco</sub>	V
Vo	Output voltage	3-state			0	3.6	V
				1.2 V		-3	
				1.4 V to 1.6 V		-6	
I <sub>OH</sub>	High-level output current			1.65 V to 1.95 V		-8	mA
				2.3 V to 2.7 V		-9	
				3 V to 3.6 V		-12	
				1.1 V to 1.2 V		3	
				1.4 V to 1.6 V		6	
I <sub>OL</sub>	Low-level output cu	ırrent		1.65 V to 1.95 V		8	mA
				2.3 V to 2.7 V		9	
				3 V to 3.6 V		12	
Δt/Δν	Input transition rise	or fall rate				5	ns/V
T <sub>A</sub>	Operating ambient	temperature			-40	125	°C

#### 6.4 Thermal Information

		SN74AVC4T245-Q1	
	THERMAL METRIC <sup>(1)</sup>	RGY (VQFN)	UNIT
		16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	37.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	54.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	15.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	3.5	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

# 6.5 Electrical Characteristics (1) (2)

over recommended operating ambient temperature range (unless otherwise noted)

PARAMETER	TEST CONDIT	IONS	V <sub>CCA</sub>	V <sub>CCB</sub>	T <sub>A</sub>	MIN	TYP	MAX	UNIT
	$I_{OH} = -100 \ \mu A$		1.2 V to 3.6 V	1.2 V to 3.6 V	$T_A = -40$ °C to 125°C	V <sub>CCO</sub> - 0.2			
	$I_{OH} = -3 \text{ mA}$		1.2 V	1.2 V	$T_A = 25^{\circ}C$		0.95		
	I <sub>OH</sub> = -6 mA		1.4 V	1.4 V	$T_A = -40^{\circ}C$ to 125°C	1.05			
V <sub>OH</sub>	$I_{OH} = -8 \text{ mA}$	$V_I = V_{IH}$	1.65 V	1.65 V	$T_A = -40$ °C to 125°C	1.2			V
	$I_{OH} = -9 \text{ mA}$		2.3 V	2.3 V	$T_A = -40$ °C to 125°C	1.75			
	I <sub>OH</sub> = -12 mA		3 V	3 V	$T_A = -40^{\circ}C$ to 125°C	2.3			

 $<sup>\</sup>begin{array}{ll} \hbox{(1)} & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ \end{array}$ 

Product Folder Links: SN74AVC4T245-Q1



# Electrical Characteristics(1) (2) (continued)

over recommended operating ambient temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDIT	TIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	T <sub>A</sub>	MIN TYP	MAX	UNIT	
		I <sub>OL</sub> = 100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V	$T_A = -40$ °C to 125°C		0.2		
		$I_{OL} = 3 \text{ mA}$		1.2 V	1.2 V	T <sub>A</sub> = 25°C	0.25			
		I <sub>OL</sub> = 6 mA		1.4 V	1.4 V	$T_A = -40$ °C to 125°C		0.35		
$V_{OL}$		I <sub>OL</sub> = 8 mA	$V_I = V_{IL}$	1.65 V	1.65 V	$T_A = -40$ °C to 125°C		0.45	V	
		I <sub>OL</sub> = 9 mA		2.3 V	2.3 V	$T_A = -40$ °C to 125°C		0.55		
	_	I <sub>OL</sub> = 12 mA		3 V	3 V	$T_A = -40$ °C to 125°C		0.7		
(0)	Control			1.2 V to	1.2 V to	T <sub>A</sub> = 25°C	±0.025	±0.25		
I <sub>I</sub> <sup>(3)</sup>	inputs	$V_I = V_{CCA}$ or GND		3.6 V	3.6 V	T <sub>A</sub> = -40°C to 125°C		±1.5	μA	
					0 V to	T <sub>A</sub> = 25°C	±0.1	±1		
1	A or B port	V. or V. = 0 to 3.6.		0 V	3.6 V	$T_A = -40^{\circ}C$ to 125°C		±5		
l <sub>off</sub>	A or b port	$V_I$ or $V_O = 0$ to 3.6 V	V	0 V to		T <sub>A</sub> = 25°C	±0.1	±1	μA	
				3.6 V	0 V	$T_A = -40$ °C to 125°C		±5		
		V – V or CND				T <sub>A</sub> = 25°C	±0.5	±2.5		
l <sub>OZ</sub>	A or B port	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND, $\overline{C}$	DE = V <sub>IH</sub>	3.6 V	3.6 V	$T_A = -40$ °C to 125°C		±5	μA	
					1.2 V to 3.6 V	1.2 V to 3.6 V	$T_A = -40$ °C to 125°C		8	
		$V_I = V_{CCI}$ or GND, $I_O = 0$		0 V to	T <sub>A</sub> = 25°C		-2			
I <sub>CCA</sub> (	3)		$V_I = V_{CCI}$ or GND, $I_O = 0$	$V_I = V_{CCI}$ or GND, $I_O = 0$	0 V	3.6 V	T <sub>A</sub> = -40°C to 125°C		-11	μΑ
				0 V to 3.6 V	0 V	T <sub>A</sub> = -40°C to 125°C		8		
				1.2 V to 3.6 V	1.2 V to 3.6 V	$T_A = -40^{\circ}C$ to 125°C		8		
I <sub>CCB</sub> (	3)	$V_I = V_{CCI}$ or GND, $I_0$	<sub>O</sub> = 0	0 V	0 V to 3.6 V	T <sub>A</sub> = -40°C to 125°C		8	μΑ	
		, ,	-	0 1/ +-		T <sub>A</sub> = 25°C		-2		
				0 V to 3.6 V	0 V	T <sub>A</sub> = -40°C to 125°C		-11		
I <sub>CCA</sub> -	+ I <sub>CCB</sub>	$V_I = V_{CCI}$ or GND, $I_0$	O = 0	1.2 V to 3.6 V	1.2 V to 3.6 V	$T_A = -40^{\circ}\text{C to}$ 125°C		16	μΑ	
	0					T <sub>A</sub> = 25°C	3.5	4.5		
Ci	Control inputs	$V_I = 3.3 \text{ V or GND}$		3.3 V	3.3 V	T <sub>A</sub> = -40°C to 125°C		7	pF	
						T <sub>A</sub> = 25°C	6			
C <sub>io</sub>	A or B port	$V_O = 3.3 \text{ V or GND}$		3.3 V	3.3 V	T <sub>A</sub> = -40°C to 125°C			pF	

<sup>(3)</sup> All unused data inputs of the device must be held at V<sub>CCI</sub> or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

Submit Documentation Feedback

Copyright © 2009–2016, Texas Instruments Incorporated



# 6.6 Switching Characteristics: V<sub>CCA</sub> = 1.2 V

over recommended operating ambient temperature range,  $V_{CCA} = 1.2 \text{ V}$  (unless otherwise noted) (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	TYP	UNIT
			V <sub>CCB</sub> = 1.2 V	3.4	
	A		$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$	2.9	
t <sub>PHL</sub> , t <sub>PLH</sub>		В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	2.7	ns
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$	2.6	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	2.8	
			V <sub>CCB</sub> = 1.2 V	3.6	
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$	3.1	
t <sub>PHL</sub> , t <sub>PLH</sub>	В	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	2.8	ns
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$	2.6	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	2.6	
			V <sub>CCB</sub> = 1.2 V	5.6	
			V <sub>CCB</sub> = 1.5 V ± 0.1 V	4.7	
PHZ, tPLZ	ŌĒ	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V	4.3	ns
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$	3.9	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	3.7	
	ŌĒ		V <sub>CCB</sub> = 1.2 V	5	
		<del>OE</del> B	V <sub>CCB</sub> = 1.5 V ± 0.1 V	4.3	
PZH			V <sub>CCB</sub> = 1.8 V ± 0.15 V	3.9	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$	3.6	†
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	36.6	
			V <sub>CCB</sub> = 1.2 V	5	ns
			V <sub>CCB</sub> = 1.5 V ± 0.1 V	4.3	
t <sub>PZL</sub>	ŌĒ	В	V <sub>CCB</sub> = 1.8 V ± 0.15 V	3.9	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$	3.6	
			V <sub>CCB</sub> = 3.3 V ± 0.3 V	3.6	
			V <sub>CCB</sub> = 1.2 V	6.2	
			V <sub>CCB</sub> = 1.5 V ± 0.1 V	5.2	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	ŌĒ	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V	5.2	ns
			V <sub>CCB</sub> = 2.5 V ± 0.2 V	4.3	
			V <sub>CCB</sub> = 3.3 V ± 0.3 V	4.8	
			V <sub>CCB</sub> = 1.2 V	5.9	
			V <sub>CCB</sub> = 1.5 V ± 0.1 V	5.1	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	ŌĒ	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$	5	
			V <sub>CCB</sub> = 2.5 V ± 0.2 V	4.7	
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$	5.5	

Product Folder Links: SN74AVC4T245-Q1



# 6.7 Switching Characteristics, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating ambient temperature range,  $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN TYP	MAX	UNIT	
			V <sub>CCB</sub> = 1.2 V	3.2			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		11.3		
PLH, t <sub>PHL</sub>	Α	В	V <sub>CCB</sub> = 1.8 V ± 0.15 V		10.2	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		9.2		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		9.2		
			V <sub>CCB</sub> = 1.2 V	3.3			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		11.3		
PLH, tPHL	В	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V		11	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		10.7		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10.6		
			V <sub>CCB</sub> = 1.2 V	4.9			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		14.6		
<sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V		14.5	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		14.4		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		14.4		
			V <sub>CCB</sub> = 1.2 V	4.5			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		14.6	ns	
<sub>ZH</sub> , t <sub>PZL</sub>	ŌĒ	В	V <sub>CCB</sub> = 1.8 V ± 0.15 V		12.7		
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		10.8		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10.6		
			V <sub>CCB</sub> = 1.2 V	5.6			
			V <sub>CCB</sub> = 1.5 V ± 0.1 V		15.2		
PZH, tPZL	ŌĒ	А	V <sub>CCB</sub> = 1.8 V ± 0.15 V		15.2	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		15.2		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		15.2		
			V <sub>CCB</sub> = 1.2 V	5.2			
			V <sub>CCB</sub> = 1.5 V ± 0.1 V		15.3		
<sub>ZH</sub> , t <sub>PZL</sub>	ŌĒ	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		14.1	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		12.4		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		12.6		

### 6.8 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating ambient temperature range,  $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN	TYP	MAX	UNIT	
t <sub>РLН</sub> , t <sub>РНL</sub>			V <sub>CCB</sub> = 1.2 V		2.9			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$			11		
	Α	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			9.9	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$			8.9		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			8.9		
			V <sub>CCB</sub> = 1.2 V		3			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$			10.3		
t <sub>РLН</sub> , t <sub>РНL</sub>	В	А	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			9.9	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$			9.6		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			9.5		

Submit Documentation Feedback

Copyright © 2009–2016, Texas Instruments Incorporated



# Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (continued)

over recommended operating ambient temperature range,  $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN	TYP	MAX	UNIT		
			V <sub>CCB</sub> = 1.2 V		4.4				
			V <sub>CCB</sub> = 1.5 V ± 0.1 V			12.4			
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V			12.3	ns		
			V <sub>CCB</sub> = 2.5 V ± 0.2 V			12.3			
			V <sub>CCB</sub> = 3.3 V ± 0.3 V		4.4 12.4 12.3 ns				
			V <sub>CCB</sub> = 1.2 V		4.1				
t <sub>PZH</sub> , t <sub>PZL</sub>			V <sub>CCB</sub> = 1.5 V ± 0.1 V			14.2			
	ŌĒ	В	V <sub>CCB</sub> = 1.8 V ± 0.15 V			12.4	ns		
			V <sub>CCB</sub> = 2.5 V ± 0.2 V			10.3			
			V <sub>CCB</sub> = 3.3 V ± 0.3 V			9.6			
			V <sub>CCB</sub> = 1.2 V		5.4				
			V <sub>CCB</sub> = 1.5 V ± 0.1 V			13.6	ns		
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	Α	V <sub>CCB</sub> = 1.8 V ± 0.15 V			13.7			
			V <sub>CCB</sub> = 2.5 V ± 0.2 V			13.7			
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			13.7			
			V <sub>CCB</sub> = 1.2 V		5				
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$	14.9					
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	В	V <sub>CCB</sub> = 1.8 V ± 0.15 V			13.7	ns		
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		11.9				
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			11.9			

### 6.9 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating ambient temperature range,  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN	TYP	MAX	UNIT			
			V <sub>CCB</sub> = 1.2 V		2.8					
			V <sub>CCB</sub> = 1.5 V ± 0.1 V			10.7				
t <sub>PLH</sub> , t <sub>PHL</sub>	Α	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			9.6	ns			
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$			8.5				
	LH, tphL  B  A  B  ZH, tpZL  OE  A	$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			8.6					
			V <sub>CCB</sub> = 1.2 V		2.7					
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$			9.2				
t <sub>PLH</sub> , t <sub>PHL</sub>	В	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			8.9	ns			
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$			8.4				
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			8.3				
			V <sub>CCB</sub> = 1.2 V		4					
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$			11.5	ns			
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			10.2				
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		9.8					
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			9.8				
			V <sub>CCB</sub> = 1.2 V		3.8					
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$	13.8						
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			12	12 ns			
			V <sub>CCB</sub> = 2.5 V ± 0.2 V	9.8						
			V <sub>CCB</sub> = 3.3 V ± 0.3 V			9				

Product Folder Links: SN74AVC4T245-Q1



### Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (continued)

over recommended operating ambient temperature range,  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN	TYP	MAX	UNIT
t <sub>PHZ</sub> , t <sub>PLZ</sub> $\overline{\text{OE}}$			V <sub>CCB</sub> = 1.2 V		4.7		
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$			13.4	
	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			13.4	ns	
			V <sub>CCB</sub> = 2.5 V ± 0.2 V		11.2		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$				11.5
			V <sub>CCB</sub> = 1.2 V		4.5		
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$	14			
t <sub>PHZ</sub> , t <sub>PLZ</sub>	ŌĒ	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$			13.2	ns
			V <sub>CCB</sub> = 2.5 V ± 0.2 V			11.2	1.2
l			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			10.2	

### 6.10 Switching Characteristics: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating ambient temperature range,  $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub>	MIN TYP	MAX	UNIT	
			V <sub>CCB</sub> = 1.2 V	2.9			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		10.6		
t <sub>PLH</sub> , t <sub>PHL</sub>	А	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		9.5	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		8.3		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		7.9		
			V <sub>CCB</sub> = 1.2 V	2.6			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		9.2		
t <sub>PLH</sub> , t <sub>PHL</sub>	В	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		8.4	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		8		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		7.8		
			V <sub>CCB</sub> = 1.2 V	3.8			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		13.7		
PHZ, <sup>†</sup> PLZ	ŌĒ	A	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		10.2	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		8.8		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		8.8		
			V <sub>CCB</sub> = 1.2 V	3.7			
		В	$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		13.7	ns	
$t_{PHZ}$ , $t_{PLZ}$	ŌĒ		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		11.8		
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		9.7		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		8.8		
			V <sub>CCB</sub> = 1.2 V	4.8			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		14.3		
$t_{PHZ}$ , $t_{PLZ}$	ŌĒ	Α	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		13.3	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		10.6		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		11.6		
			V <sub>CCB</sub> = 1.2 V	5.3			
			$V_{CCB} = 1.5 \text{ V} \pm 0.1 \text{ V}$		14.3		
t <sub>PHZ</sub> , t <sub>PLZ</sub>	ŌĒ	В	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		13.1	ns	
			$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		11.4		
			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		11.2		

Submit Documentation Feedback

Copyright © 2009–2016, Texas Instruments Incorporated



# **6.11 Operating Characteristics**

 $T_{\Delta} = 25^{\circ}C$ 

	PARAMETER		TEST CONDITIONS	V <sub>CCA</sub>	ТҮР	UNIT
				V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2 V	1	
			$C_L = 0$ ,	$V_{CCA} = V_{CCB} = 1.5 \text{ V}$	1	
		Outputs enabled	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 \text{ V}$	1	
		onasioa	$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 \text{ V}$	1.5	
	A to B			$V_{CCA} = V_{CCB} = 3.3 \text{ V}$	2	
	AIUB			$V_{CCA} = V_{CCB} = 1.2 \text{ V}$		
			$C_1 = 0$	$V_{CCA} = V_{CCB} = 1.5 \text{ V}$		
		Outputs disabled	f = 10  MHz,	$V_{CCA} = V_{CCB} = 1.8 \text{ V}$	1	
		0.000.00	$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 \text{ V}$		
<b>(</b> 1)				$V_{CCA} = V_{CCB} = 3.3 \text{ V}$		pF
C <sub>pdA</sub> (1)				$V_{CCA} = V_{CCB} = 1.2 \text{ V}$	12	рг
		enabled f = t <sub>r</sub> :	$C_L = 0$ ,	$V_{CCA} = V_{CCB} = 1.5 \text{ V}$	12.5	
			f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 \text{ V}$	13	
		Chabled	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V	14	
				$V_{CCA} = V_{CCB} = 3.3 \text{ V}$	15	
				V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2 V		
			$C_L = 0$ ,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5 V		
			f = 10 MHz,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	1	
		disabled	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V		
				V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V		
				$V_{CCA} = V_{CCB} = 1.2 \text{ V}$	12	
			$C_L = 0$ ,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5 V	12.5	
		Outputs enabled	f = 10  MHz,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	13	
		enabled	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V	14	
	A (- D			$V_{CCA} = V_{CCB} = 3.3 \text{ V}$	15	
	A to B			$V_{CCA} = V_{CCB} = 1.2 \text{ V}$		
			$C_1 = 0$	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5 V		
		Outputs disabled	f = 10  MHz,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	1	
		disabica	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V		
<b>(1)</b>				$V_{CCA} = V_{CCB} = 3.3 \text{ V}$		_
PpdB (1)				V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2 V	1	pF
			$C_L = 0$ ,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5 V	1	
	D. I. A	Outputs enabled	f = 10 MHz,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	1	
		enabled	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V	1	
				V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V	2	
	B to A			V <sub>CCA</sub> = V <sub>CCB</sub> = 1.2 V		
			$C_L = 0$ ,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.5 V		
		Outputs disabled	$C_L = 0$ , $f = 10 \text{ MHz}$ ,	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V	1	
		uisabieu	$t_r = t_f = 1 \text{ ns}$	V <sub>CCA</sub> =V <sub>CCB</sub> = 2.5 V		
				$V_{CCA} = V_{CCB} = 3.3 \text{ V}$		

<sup>(1)</sup> Power dissipation capacitance per transceiver

# TEXAS INSTRUMENTS

### 6.12 Typical Characteristics

 $T_A = 25^{\circ}C$ 

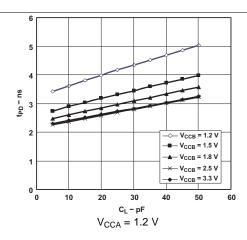


Figure 1. Typical Propagation Delay (A to B) vs Load Capacitance

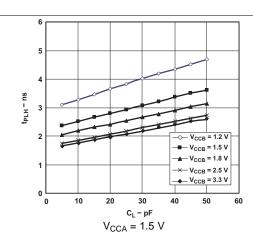


Figure 2. Typical Propagation Delay (A to B) vs Load Capacitance

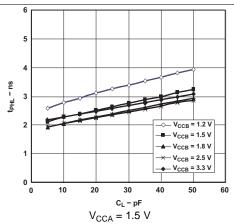


Figure 3. Typical Propagation Delay (A to B) vs Load Capacitance

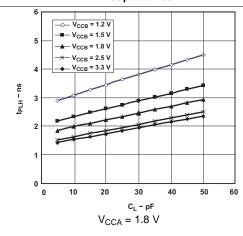


Figure 4. Typical Propagation Delay (A to B) vs Load Capacitance

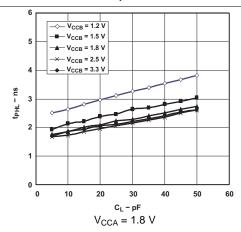


Figure 5. Typical Propagation Delay (A to B) vs Load Capacitance

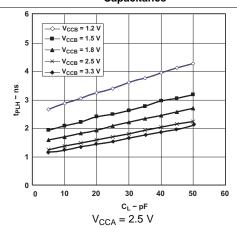


Figure 6. Typical Propagation Delay (A to B) vs Load Capacitance



### **Typical Characteristics (continued)**



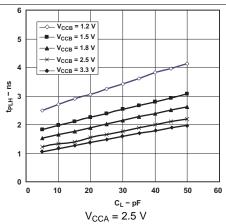


Figure 7. Typical Propagation Delay (A to B) vs Load Capacitance

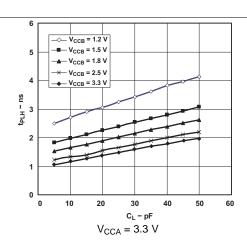


Figure 8. Typical Propagation Delay (A to B) vs Load Capacitance

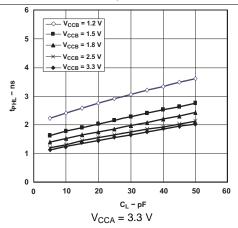


Figure 9. Typical Propagation Delay (A to B) vs Load Capacitance

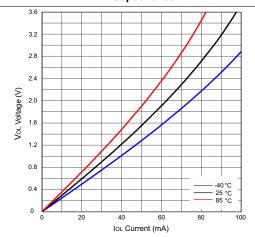


Figure 10. Low-Level Output Voltage (V<sub>OL</sub>) vs Low-Level Current (I<sub>OL</sub>)

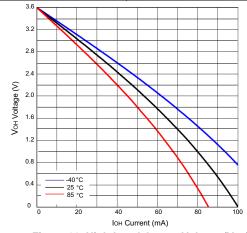


Figure 11. High-Level Output Voltage ( $V_{OH}$ ) vs High-Level Current ( $I_{OH}$ )

Copyright © 2009–2016, Texas Instruments Incorporated

Input

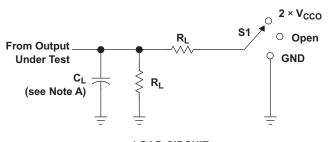
Output

t<sub>PLH</sub>

**V<sub>CCA</sub>** 



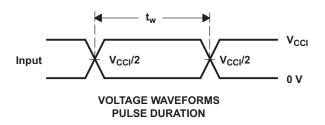
### 7 Parameter Measurement Information

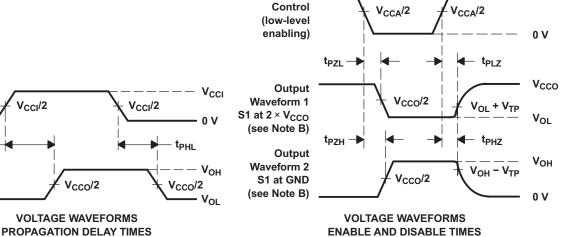


TEST	S1
t <sub>pd</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>CCO</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

V <sub>cco</sub>	CL	R <sub>L</sub>	V <sub>TP</sub>
1.2 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V ± 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V ± 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
3.3 V ± 0.3 V	15 pF	<b>2 k</b> Ω	0.3 V





Output

NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

V<sub>CCI</sub>/2

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$ ,  $dv/dt \geq$  1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

Figure 12. Load and Circuit and Voltage Waveforms

Submit Documentation Feedback

Copyright © 2009-2016, Texas Instruments Incorporated



### 8 Detailed Description

#### 8.1 Overview

The SN74AVC4T245-Q1 is a 4-bit, dual-supply noninverting bidirectional voltage level translation device. Ax pins and control pins (1DIR, 2DIR,1 $\overline{OE}$ , and 2 $\overline{OE}$ ) are supported by V<sub>CCA</sub>, and Bx pins are supported by V<sub>CCB</sub>. The A port is able to accept I/O voltages ranging from 1.2 V to 3.6 V, while the B port can accept I/O voltages from 1.2 V to 3.6 V. A high on DIR allows data transmission from Ax to Bx and a low on DIR allows data transmission from Bx to Ax when  $\overline{OE}$  is set to low. When  $\overline{OE}$  is set to high, both Ax and Bx pins are in the high-impedance state.

### 8.2 Functional Block Diagram

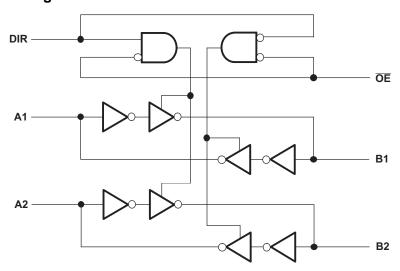


Figure 13. Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245-Q1

Product Folder Links: SN74AVC4T245-Q1



#### 8.3 Feature Description

### 8.3.1 Fully Configurable Dual-Rail Design

Both  $V_{CCA}$  and  $V_{CCB}$  can be supplied at any voltage between 1.2 V and 3.6 V; thus, making the device suitable for translating between any of the low voltage nodes (1.2 V, 1.8 V, 2.5 V, and 3.3 V).

### 8.3.2 Supports High Speed Translation

The SN74AVC4T245-Q1 device can support high data rate applications. The translated signal data rate can be up to 380 Mbps when the signal is translated from 1.8 V to 3.3 V.

### 8.3.3 I<sub>off</sub> Supports Partial-Power-Down Mode Operation

I<sub>off</sub> prevents backflow current by disabling I/O output circuits when the device is in partial-power-down mode.

#### 8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74AVC4T245-Q1 device.

Table 1. Function Table (Each 2-Bit Section)<sup>(1)</sup>

CONTRO	L INPUTS	OUTPUT O	CIRCUITS	OPERATION	
ŌĒ	DIR	A PORT	B PORT	OPERATION	
L	L	Enabled	Hi-Z	B data to A bus	
L	Н	Hi-Z	Enabled	A data to B bus	
Н	X	Hi-Z	Hi-Z	Isolation	

(1) Input circuits of the data I/Os are always active.



### 9 Application and Implementation

#### **NOTE**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The SN74AVC4T245-Q1 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The SN74AVC4T245-Q1 device is ideal for use in applications where a push-pull driver is connected to the data I/Os. The maximum data rate can be up to 380 Mbps when the device translates a signal from 1.8 V to 3.3 V.

### 9.2 Typical Application

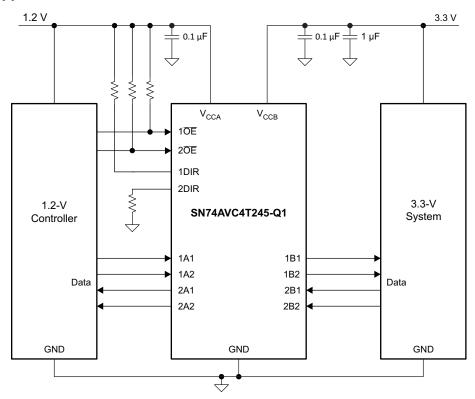


Figure 14. Typical Application Diagram



### **Typical Application (continued)**

#### 9.2.1 Design Requirements

Table 2 lists the parameters for this design example.

**Table 2. Design Parameters** 

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.2 V
Output voltage range	3.3 V

#### 9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74AVC4T245-Q1 device to determine the input voltage range. For a valid logic high, the value must exceed the  $V_{IH}$  of the input port. For a valid logic low, the value must be less than the  $V_{IL}$  of the input port. For this example, the input voltage is 1.2 V.
- Output voltage range
  - Use the supply voltage of the device that the SN74AVC4T245-Q1 device is driving to determine the output voltage range. For this example, the output voltage is 3.3 V.

#### 9.2.3 Application Curve

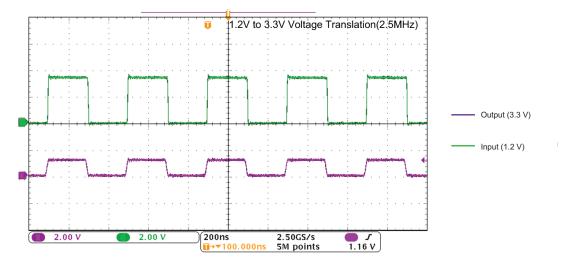


Figure 15. Translation Up (1.2 V to 3.3 V) at 2.5 MHz



### 10 Power Supply Recommendations

The SN74AVC4T245-Q1 device uses two separate configurable power-supply rails:  $V_{CCA}$  and  $V_{CCB}$ .  $V_{CCA}$  accepts any supply voltage from 1.2 V to 3.6 V, and  $V_{CCB}$  accepts any supply voltage from 1.2 V to 3.6 V. The A port and B port are designed to track  $V_{CCA}$  and  $V_{CCB}$  respectively, allowing for low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

The output-enable  $(\overline{OE})$  input circuit is designed so that it is supplied by  $V_{CCA}$ ; when the  $\overline{OE}$  input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to V<sub>CCA</sub> through a pullup resistor and must not be enabled until V<sub>CCA</sub> and V<sub>CCB</sub> are fully ramped and stable. The minimum value of the pullup resistor to V<sub>CCA</sub> is determined by the current-sinking capability of the driver.

#### 11 Layout

#### 11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Place pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals, depending on the system requirements.

### 11.2 Layout Example

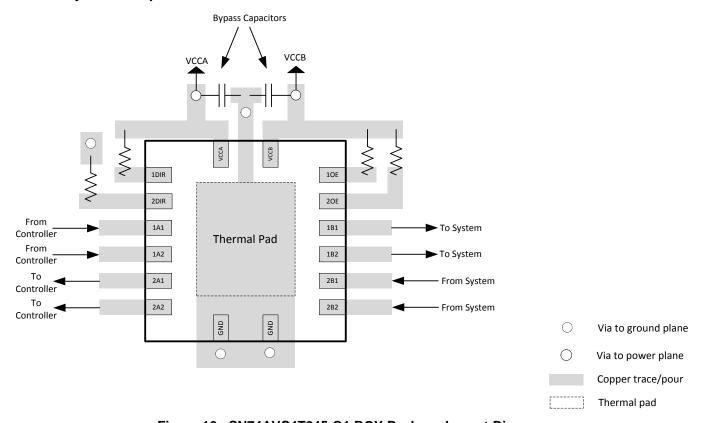


Figure 16. SN74AVC4T245-Q1 RGY Package Layout Diagram

Product Folder Links: SN74AVC4T245-Q1

Copyright © 2009-2016, Texas Instruments Incorporated



### 12 Device and Documentation Support

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

- IC Package Thermal Metrics application report (SPRA953)
- Implications of Slow or Floating CMOS Inputs application report (SCBA004)

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community T's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.2 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the mostcurrent data available for the designated device. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.



### PACKAGE OPTION ADDENDUM

23-Oct-2015

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
74AVC4T245QRGYRQ1	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



# **PACKAGE OPTION ADDENDUM**

23-Oct-2015

#### OTHER QUALIFIED VERSIONS OF SN74AVC4T245-Q1:

◆ Catalog: SN74AVC4T245

www.ti.com

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Oct-2015

### TAPE AND REEL INFORMATION





A0	
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVC4T245QRGYRQ1	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

www.ti.com 23-Oct-2015



#### \*All dimensions are nominal

Device Package Type		Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)
74AVC4T245QRGYRQ1	VQFN	RGY	16	3000	367.0	367.0	35.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



# RGY (R-PVQFN-N16)

### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (R-PVQFN-N16)

# PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

#### Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity www.ti.com/wirelessconnectivity